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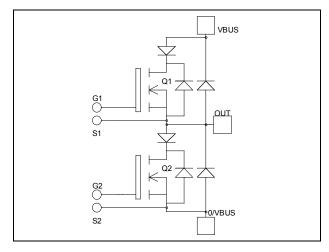


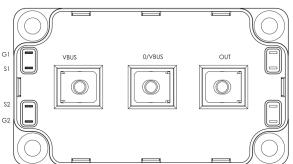




Phase leg Series & parallel diodes MOSFET Power Module

$$\begin{split} V_{DSS} &= 1000V \\ R_{DSon} &= 130 \text{m}\Omega \text{ typ } \text{@ Tj} = 25^{\circ}\text{C} \\ I_D &= 65\text{A} \text{ @ Tc} = 25^{\circ}\text{C} \end{split}$$





Application

- Motor control
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		1000	V
Ţ	Continuous Drain Current	$T_c = 25$ °C	65	
I_D	Continuous Diani Current	$T_c = 80$ °C	49	A
I_{DM}	Pulsed Drain current		240	
V_{GS}	Gate - Source Voltage		±30	V
R_{DSon}	Drain - Source ON Resistance		156	mΩ
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	1250	W
I_{AR}	Avalanche current (repetitive and non repetitive)		24	A
E_{AR}	Repetitive Avalanche Energy		30	mJ
E_{AS}	Single Pulse Avalanche Energy		1300	1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$	$T_j = 25$ °C			600	μΑ
		$V_{GS} = 0V, V_{DS} = 800V$	$T_j = 125$ °C			2	mA
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 32.5A$			130	156	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 6mA$		3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$				±450	nA

Dynamic Characteristics

•	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		15.2		
C_{oss}	Output Capacitance	$V_{\rm DS} = 25 V$		2.6		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		0.42		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		562		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 500 \text{V}$		75		nC
Q_{gd}	Gate – Drain Charge	$I_D = 65A$		363		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		9		ns
T_{r}	Rise Time	$V_{GS} = 15V$		9		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 667V$ $I_{\text{D}} = 65A$		50		
T_{f}	Fall Time	$R_G = 0.5\Omega$		24		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		2.13		
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 667V$ $I_D = 65A, R_G = 0.5\Omega$		0.46		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		4.4		τ.
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 667V$ $I_D = 65A, R_G = 0.5\Omega$		0.57		mJ
R_{thJC}	Junction to Case Thermal Resistance				0.1	°C/W

Series diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage	e		1000			V
I_{RM}	Maximum Reverse Leakage Current	$V_{R} = 1000V$				350	μA
I_F	DC Forward Current		$T_{c} = 100^{\circ}C$		120		A
		$I_F = 120A$			1.9	2.5	
V_{F}	Diode Forward Voltage	$I_F = 240A$			2.2		V
		$I_F = 120A$	$T_j = 125$ °C		1.7		í
+			$T_j = 25^{\circ}C$		280		ns
ι _{rr}		$I_F = 120A$ $V_R = 667V$	$T_j = 125$ °C		350		115
Q _{rr}	Reverse Recovery Charge	$di/dt = 400A/\mu s$	$T_j = 25^{\circ}C$		1520		пC
			$T_{j} = 125^{\circ}C$		7200		пС
R_{thJC}	Junction to Case Thermal Resistance					0.46	°C/W



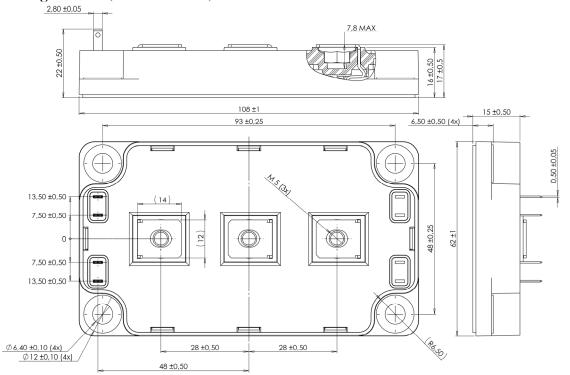
Parallel diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage	e		1000			V
I_{RM}	Maximum Reverse Leakage Current	$V_R = 1000V$				350	μA
I_{F}	DC Forward Current		$T_c = 100$ °C		120		A
		$I_{\rm F} = 120A$			1.9	2.5	
V_{F}	Diode Forward Voltage	$I_F = 240A$			2.2		V
		$I_F = 120A$	$T_j = 125$ °C		1.7		
t _{rr}	Reverse Recovery Time		$T_j = 25$ °C		280		
		$I_F = 120A$ $V_R = 667V$	$T_{j} = 125^{\circ}C$		350		ns
Qrr	Reverse Recovery Charge	$di/dt = 400A/\mu s$	$T_j = 25^{\circ}C$		1520		C
		•	$T_{j} = 125^{\circ}C$		7200		nC
R_{thJC}	Junction to Case Thermal Resistance		_			0.46	°C/W

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz						V
T_{J}	Operating junction temperature range			-40		150	
T _{STG}	Storage Temperature Range					125	°C
$T_{\rm C}$	Operating Case Temperature	-40		100			
Torque	Mounting targue	To heatsink	M6	3 5	5	N.m	
Torque	Mounting torque For terminals		M5	2		3.5	IN.III
Wt	Package Weight	•				300	g

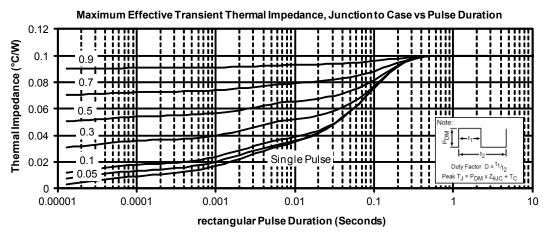
SP6 Package outline (dimensions in mm)

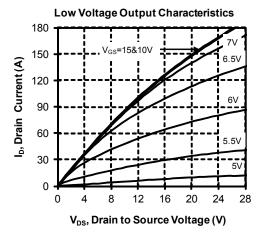


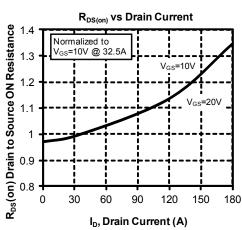
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

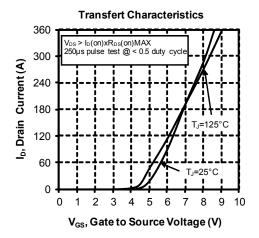


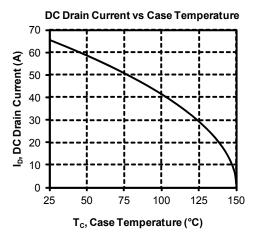
Typical Performance Curve



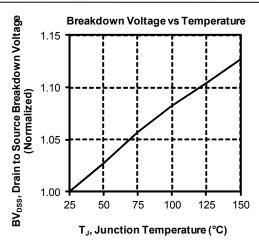


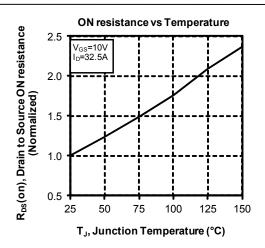


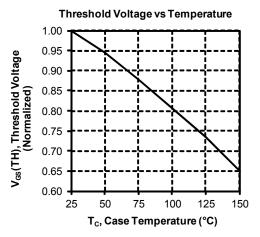


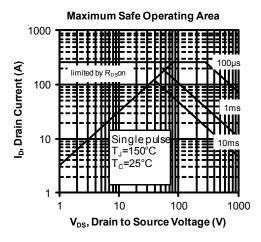


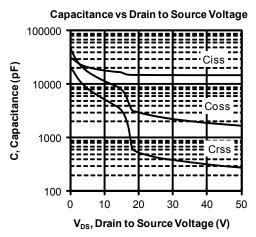


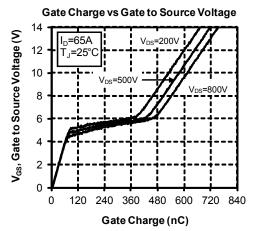






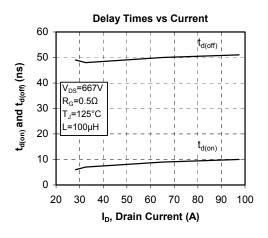


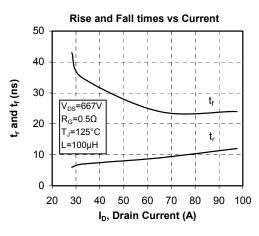


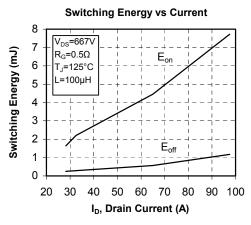


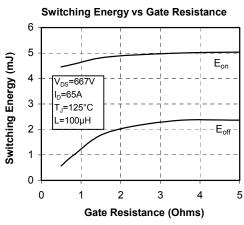
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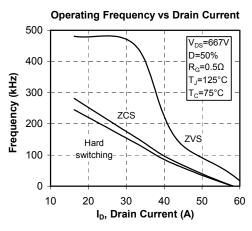


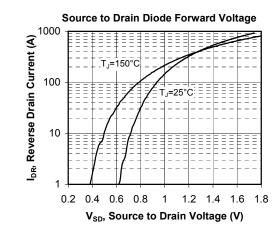














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